

**EAST - [10726050.wsp:1]**

File View Edit Tools Window Help

Drafts Pending Active

- L1: (112) ((integrated adj circuit) or "IC") and ((non adj flc))
- L2: (159) ((integrated adj circuit) or "IC") and ((non adj flc))
- L3: (52) 2 and (terminal and (solder or ball or pad))
- L4: (9) 3 and (capacitor and (insulator\$4 or dielectric))
- L5: (4) "6686659"
- L6: (7) Backward citation search 1
- L9: (12) Backward citation search 2
- L10: (20) Forward citation search 2
- L12: (2) 11 and decoupl\$4
- L11: (32) 3 not (4 5 6 7 9 10)

Failed

Saved

- S1: (290) substrate and ((bump or solder or (solder adj ball))
- S2: (59) seshan-krishna.in.
- S3: (24) ("4141022"|"5605861"|"5770490"|"5882965"|"5937289"|"5
- S4: (3) seshan-krishna.in. and ("IC" or (integrated adj circu
- S5: (1) (US-20040108596-\$).did.
- S6: (1) US-20040108596-A1.DID. and (float\$4 or (non-float\$4))
- S7: (24) ("4141022"|"5605861"|"5770490"|"5882965"|"5937289"|"5
- S8: (7) ("4273859"|"5808853"|"6094090"|"6175345"|"6222246"|"62

Search | Browse | Options | Clear  
DBs: US-PGPUB; USPAT; EPO; JPO; DERVENT; IBM\_TDB  
Defined operator: OR

3 and (capacitor and (insulator\$4 or dielectric))

BRS form ISR form Image Text HTML

U	I	PT	P	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	
1	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030234660	20031225	10	Direct landing technology for wafer probe A1	324/765		
2	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20020119583	20020829	23	Selectable decoupling capacitors for integrated circuit and methods of use A1	438/17	257/E23.079; 257/E23.171	
3	<input type="checkbox"/>	<input checked="" type="checkbox"/>	<input type="checkbox"/>	US 20020068267	20020124	24	Deep trench semiconductor capacitors having reverse bias diodes for implantable medical devices	257/301	257/106; 257/E21.396;	
4	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6686659	B2	22	Selectable decoupling capacitors for integrated circuit and methods of use	257/737	257/532; 257/E23.079;	
5	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6484054	B2	20021119	23	Deep trench semiconductor capacitors having reverse bias diodes for implantable medical devices	607/2	257/E21.396; 257/E27.048;
6	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6452514	B1	20020917	17	Capacitive sensor and array	341/33	178/18.06; 341/22
7	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6040609	A	20000321	9	Field-effect transistor for one-time programmable nonvolatile memory element	257/390	257/356; 257/391;
8	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 5358514	A	19941025	17	Implantable microdevice with self-attaching electrodes	607/61	607/118

Hit Details HTML

Ready